August 1996

### NM93CS06L/CS46L/CS56L/CS66L 256-/1024-/2048-/4096-Bit Serial EEPROM with Extended Voltage (2.7V to 5.5V) and Data Protect (MICROWIRE™ Bus Interface)

#### **General Description**

The NM93CS06L/CS46L/CS56L/CS66L devices are 256/1024/2048/4096 bits, respectively, of non-volatile electrically erasable memory divided into 16/64/128/256 x 16-bit registers (addresses). The NM93CSxxL Family functions in an extended voltage operating range, and is fabricated using National Semiconductor's floating gate CMOS technology for high reliability, high endurance and low power consumption. N registers (N  $\leq$  16, N  $\leq$  64, N  $\leq$  128, N  $\leq$  256) can be protected against data modification by programming the Protect Register with the address of the first register to be protected against data modification. (All registers greater than, or equal to, the selected address are then protected from further change.) Additionally, this address can be "locked" into the device, making all future attempts to change data impossible.

These devices are available in both SO and TSSOP packages for small space considerations.

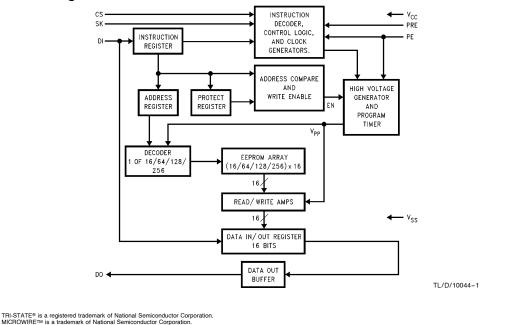
The serial interface that controls these EEPROMs is MICROWIRE compatible, providing simple interfacing to standard microcontrollers and microprocessors. There are a total of 10 instructions, 5 which operate on the EEPROM

memory and 5 which operate on the Protect Register. The memory instructions are READ, WRITE, WRITE ALL, WRITE ENABLE, and WRITE DISABLE. The Protect register instructions are PRREAD, PRWRITE, PRCLEAR, PRDISABLE and PRENABLE.

#### **Features**

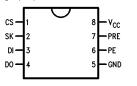
- Sequential register read
- Write protection in a user defined section of memory
- 2.7V to 5.5V operating range in all modes
- Typical active current of 200 μA; typical standby current of 1 μA
- No erase required before write
- Reliable CMOS floating gate technology
- MICROWIRE compatible serial I/O
- Self timed write cycle
- Device status during programming mode
- 40 year data retention
- Endurance: 10<sup>6</sup> data changes
- Packages Available: 8-pin SO, 8-pin DIP, and 8-pin TSSOP

#### **Block Diagram**



### **Connection Diagrams**

Dual-In-Line Package (N) 8-Pin SO Package (M8) and 8-Pin TSSOP Package (MT8)



Top View

See NS Package Number N08E (N) See NS Package Number M08A (M8) See NS Package Number MTC08 (MT8)

#### Pin Names

CS	Chip Select			
SK	Serial Data Clock			
DI	Serial Data Input			
DO	Serial Data Output			
GND	Ground			
PE	Program Enable			
PRE	Protect Register Enable			
V <sub>CC</sub>	Power Supply			

### **Ordering Information**

#### Commercial Temp. Range (0°C to $\,+\,70^{\circ}$ C)

TL/D/10044-2

Order Number
NM93CS06LN/NM93CS46LN/NM93CS56LN/NM93CS66LN
NM93CS06LM8/NM93CS46LM8/NM93CS56LM8/NM93CS66LM8
NIMO3CS/61 MT8/NIMO3CS61 MT8/NIMO3CS661 MT8

#### Extended Temp. Range ( $-\,40^{\circ}\text{C}$ to $\,+\,85^{\circ}\text{C})$

Order Number
NM93CS06LEN/NM93CS46LEN/NM93CS56LEN/NM93CS66LEN
NM93CS06LEM8/NM93CS46LEM8/NM93CS56LEM8/NM93CS66LEM8
NM93CS46LEMT8/NM93CS56LEMT8/NM93CS66LEMT8

#### Automotive Temp. Range ( $-40^{\circ}$ C to $+125^{\circ}$ C)

Order Number
NM93CS06LVN/NM93CS46LVN/NM93CS56LVN/NM93CS66LVN
NM93CS06LVM8/NM93CS46LVM8/NM93CS56LVM8/NM93CS66LVM8
NM93CS46LVMT8/NM93CS56LVMT8/NM93CS66LVMT8

#### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \mbox{Ambient Storage Temperature} & -65^{\circ}\mbox{C to } +150^{\circ}\mbox{C} \\ \mbox{All Input or Output Voltages} & +6.5\mbox{V to } -0.3\mbox{V} \\ \mbox{with Respect to Ground} \end{array}$ 

Lead Temperature (Soldering, 10 sec.) + 300°C ESD rating 2000V

### **Operating Conditions**

Ambient Operating Temperature

NM93CSxxL

NM93CSxxLE

0°C to +70°C

-40°C to +85°C

Power Supply (V<sub>CC</sub>) Range
Read Mode 2.0
WRALL Bulk Programming 3.0
All Other Modes 2.8

2.0V to 5.5V 3.0V to 5.5V 2.5V to 5.5V

### DC and AC Electrical Characteristics: $2V < V_{CC} < 4.5V$

Symbol	Parameter	Conditions	Min	Max	Units	
I <sub>CCA</sub>	Operating Current	$CS = V_{IH}$ , $SK = 250 \text{ kHz}$		1		
Iccs	Standby Current	CS = V <sub>IL</sub>		50	μΑ	
I <sub>IL</sub> I <sub>OL</sub>	Input Leakage Output Leakage	V <sub>IN</sub> = 0V to V <sub>CC</sub> (Note 4)		±1	μΑ	
$V_{IL}$ $V_{IH}$	Input Low Voltage Input High Voltage		−0.1 0.8 V <sub>CC</sub>	0.15 V <sub>CC</sub> V <sub>CC</sub> + 1	V	
V <sub>OL</sub> V <sub>OH</sub>	Output Low Voltage Output High Voltage	$I_{OL} = 10 \mu A$ $I_{OH} = -10 \mu A$	0.9 V <sub>CC</sub>	0.1 V <sub>CC</sub>	V	
f <sub>SK</sub>	SK Clock Frequency	(Note 5)	0	250	kHz	
t <sub>SKH</sub>	SK High Time		1		μs	
t <sub>SKL</sub>	SK Low Time		1		μs	
t <sub>SKS</sub>	SK Setup Time	SK must be at V <sub>IL</sub> for t <sub>SKS</sub> before CS goes high	0.2		μs	
t <sub>CS</sub>	Minimum CS Low Time	(Note 2)	1		μs	
t <sub>CSS</sub>	CS Setup Time		0.2		μs	
t <sub>PRES</sub>	PRE Setup Time		0.2		μs	
t <sub>PES</sub>	PE Setup Time		0.2		μs	
t <sub>DIS</sub>	DI Setup Time		0.4		μs	
t <sub>DH</sub>	DO Hold Time		70		ns	
t <sub>CSH</sub>	CS Hold Time		0		μs	
t <sub>PEH</sub>	PE Hold Time		0.4		μs	
t <sub>PREH</sub>	PRE Hold Time		0.4		μs	
t <sub>DIH</sub>	DI Hold Time		0.4		μs	
t <sub>PD1</sub>	Output Delay to "1"			2	μs	
t <sub>PD0</sub>	Output Delay to "0"			2	μs	
t <sub>SV</sub>	CS to Status Valid			1	μs	
t <sub>DF</sub>	CS to DO in TRI-STATE®	CS = V <sub>IL</sub>		0.4	μs	
t <sub>WP</sub>	Write Cycle Time			15	ms	

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Symbol	Parameter	Part Number	Conditions	Min	Max	Units
I <sub>CCA</sub>	Operating Current CMOS Input Levels		$CS = V_{IH}, SK = 1.0 MHz$		1	mA
Iccs	Standby Current		CS = V <sub>IL</sub>		50	μΑ
I <sub>IL</sub> I <sub>OL</sub>	Input Leakage Output Leakage		V <sub>IN</sub> = 0V to V <sub>CC</sub> (Note 4)		±1	μΑ
V <sub>IL</sub> V <sub>IH</sub>	Input Low Voltage Input High Voltage			-0.1 2	0.8 V <sub>CC</sub> +1	V
V <sub>OL1</sub> V <sub>OH1</sub>	Output Low Voltage Output High Voltage		$I_{OL} = 2.1 \text{ mA}$ $I_{OL} = 400 \mu\text{A}$	2.4V	0.4	٧
V <sub>OL2</sub> V <sub>OH2</sub>	Output Low Voltage Output High Voltage		$I_{OL} = 10 \mu A$ $I_{OL} = -10 \mu A$	V <sub>CC</sub> -0.2	0.2	V
f <sub>SK</sub>	SK Clock Frequency		(Note 5)	0	1	MHz
t <sub>SKH</sub>	SK High Time	NM93CS06L-NM93CS66L NM93CS06LE-NM93CS66LE		250 300		ns
t <sub>SKL</sub>	SK Low Time			250		ns
t <sub>SKS</sub>	SK Setup Time		SK must be at V <sub>IL</sub> for t <sub>SKS</sub> before CS goes High	50		ns
t <sub>CS</sub>	Minimum CS Low Time		(Note 2)	250		ns
t <sub>CSS</sub>	CS Setup Time			50		ns
t <sub>PRES</sub>	PRE Setup Time			50		ns
t <sub>DH</sub>	DO Hold Time			70		ns
t <sub>PES</sub>	PE Setup Time			50		ns
t <sub>DIS</sub>	DI Setup Time			100		ns
t <sub>CSH</sub>	CS Hold Time			0		ns
t <sub>PEH</sub>	PE Hold Time			250		ns
t <sub>PREH</sub>	PRE Hold Time			50		ns
t <sub>DIH</sub>	DI Hold Time			20		ns
t <sub>PD1</sub>	Output Delay to "1"				500	ns
t <sub>PD0</sub>	Output Delay to "0"				500	ns
t <sub>SV</sub>	CS to Status Valid				500	ns
t <sub>DF</sub>	CS to DO in TRI-STATE		CS = V <sub>IL</sub>		100	ns
t <sub>WP</sub>	Write Cycle Time				10	ms

# Capacitance (Note 3) T<sub>A</sub> = 25°C f = 1 MHz

Symbol	Test	Max	Units
C <sub>OUT</sub>	Output Capacitance	5	pF
C <sub>IN</sub>	Input Capacitance	5	pF

Note 1: Stress ratings above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and operation of the device at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: CS (Chip Select) must be brought low (to V<sub>IL</sub>) for an interval of t<sub>CS</sub> in order to reset all internal device registers (device reset) prior to beginning another opcode cycle (This is shown in the opcode diagrams in the following pages).

Note 3: This parameter is periodically sampled and not 100% tested.

Note 4: Typical leakage values are in the 20 nA range.

Note 5: The shortest allowable SK clock period =  $1/f_{SK}$  (as shown under the  $f_{SK}$  parameter). Maximum SK clock speed (minimum SK period) is determined by the interaction of several AC parameters stated in the datasheet. Within this SK period, both t<sub>SKH</sub> and t<sub>SKL</sub> limits must be observed. Therefore, it is not allowable to set  $1/f_{\mbox{SK}} = t_{\mbox{SKH (minimum)}} + t_{\mbox{SKL (minimum)}}$  for shorter SK cycle time operation,

#### **AC Test Conditions**

V <sub>CC</sub> Range	V <sub>IL</sub> /V <sub>IH</sub> Input Levels	V <sub>IL</sub> /V <sub>IH</sub> Timing Level	V <sub>OL</sub> /V <sub>OH</sub> Timing Level	I <sub>OL</sub> /I <sub>OH</sub>
$2.0 \text{V} \leq \text{V}_{\text{CC}} < 4.5 \text{V}$ (Extended Voltage Levels)	0.3V/1.8V	1.0V	0.8V/1.5V	±10 μA
$4.5 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V}$ (TTL Levels)	0.4V/2.4V	1.0V/2.0V	0.4V/2.4V	−2.1 mA/0.4 mA

Output Load: 1 TTL Gate ( $C_L = 100 \text{ pF}$ )

#### **Functional Description**

The extended voltage EEPROMs of the NM93CSxxL Family have 10 instructions as described below. Note that MSB of any instruction is a "1" and is viewed as a start bit in the interface sequence. For the CS06 and CS46 the next 8 bits carry the opcode and the 6-bit address for register selection. For the CS56 and CS66, the next 10 bits carry the opcode and the 8-bit address for register selection. All Data In signals are clocked into the device on the low-to-high SK transition.

#### Read and Sequential Register Read (READ):

The READ instruction outputs serial data on the D0 pin. After a READ instruction is received, the instruction and address are decoded, followed by data transfer from the selected memory register into a 16-bit serial-out shift register. A dummy bit (logical 0) precedes the 16-bit data output string. Output data changes are initiated by a low to high transition of the SK clock. In the **Sequential Read** mode of operation, the memory automatically cycles to the next register after each 16 data bits are clocked out. The dummy-bit is suppressed in this mode and a continuous string of data is obtained.

#### Write Enable (WEN):

When  $V_{CC}$  is applied to the part, it "powers up" in the Write Disable (WDS) state. Therefore, all programming modes must be preceded by a Write Enable (WEN) instruction. Once a Write Enable instruction is executed, programming remains enabled until a Write Disable (WDS) instruction is executed or  $V_{CC}$  is removed from the part.

#### Write (WRITE):

The WRITE instruction is followed by 16 bits of data to be written into the specified address. After the last bit of data is allocated to the data-in (DI) pin, CS must be brought low before the next rising edge of the SK clock. This falling edge of the CS initiates the self-timed programming cycle. The PE pin **MUST** be held high while loading the WRITE instruction; however, after loading the WRITE instruction, the PE pin becomes a "don't care". The D0 pin indicates the READY/BUSY status of the chip if CS is brought high after the tcs internal. D0 = logical 0 indicates that programming is still in progress. D0 = logical 1 indicates that the register at the address specified in the instruction has been written with the data pattern specified in the instruction and that the part is ready for another instruction.

#### Write All (WRALL):

The WRALL instruction is valid only when the Protect Register has been cleared by executing a PRCLEAR instruction. The WRALL instruction will simultaneously program all registers with the data pattern specified in the instruction. Like the WRITE instruction, the PE pin **MUST** be held high while loading the WRALL instruction; however, after loading the WRITE instruction, the PE pin becomes a "don't care". As in the WRITE mode, the DO pin indicates the READY/BUSY status of the chip if CS is brought high after the total interval. This function is DISABLED if the protect register is in use to lock out a section memory.

#### Write Disable (WDS):

To protect against accidental data disturb, the WDS instruction disables all programming modes and should follow all programming operations. Execution of a READ instruction is independent of both the WEN and WDS instructions.

**Note:** For all protect register operations: If the PRE pin is not held at  $V_{IH}$ , all instructions will be applied to the EEPROM array, rather than the Protect Register.

#### **Protect Register Read (PRREAD):**

The PRREAD instruction outputs the address stored in the Protect Register on the DO pin. The PRE pin **MUST** be held high while loading the instruction sequence. Following the PRREAD instruction the 6- or 8-bit address stored in the memory protect register is transferred to the serial out shift register. As in the READ mode, a dummy bit (logical 0) precedes the 6- or 8-bit address string.

#### Protect Register Enable (PREN):

The PREN instruction is used to enable the PRCLEAR, PRWRITE, and PRDS modes. Before the PREN mode can be entered, the part must be in the Write Enable (WEN) mode. Both the PRE and PE pins **MUST** be held high while loading the instruction sequence.

Note that a PREN instruction must **immediately** precede a PRCLEAR, PRWRITE, or PRDS instruction.

#### **Protect Register Clear (PRCLEAR):**

The PRCLEAR instruction clears the address stored in the Protect Register and therefore enables **all** registers for the WRITE and WRALL instruction. The PRE and PE pins **must** be held high while loading the instruction sequence; however, after loading the PRCLEAR instruction, the PRE and PE pins become "don't care". Note that a PREN instruction must **immediately** precede a PRCLEAR instruction.

Please note that the PRCLEAR instruction and the PRWRITE instruction will both program the Protect Register with all 1s. However, the PRCLEAR instruction will allow the LAST register to be programmed, whereas the PRWRITE instruction = all 1s will PREVENT the last register from being programmed. In addition, the PRCLEAR instruction will allow the use of the WRALL command, where the PRWRITE = all 1s will lock out the Bulk programming opcode.

#### Protect Register Write (PRWRITE):

The PRWRITE instruction is used to write into the Protect Register the address of the first register to be protected. After the PRWRITE instruction is executed, all memory registers whose addresses are greater than or equal to the address specified in the Protect Register are protected from the WRITE operation. Note that before executing a PRWRITE instruction, the Protect Register must first be cleared by executing a PRCLEAR operation and the PRE and PE pins **must** be held high while loading the instruction; however, after loading the PRWRITE instruction, the PRE and PE pins become "don't care". Note that a PREN instruction must **immediately** precede a PRWRITE instruction.

#### Protect Register Disable (PRDS):

The PRDS instruction is a **ONE** TIME ONLY instruction which renders the Protect Register unalterable in the future. Therefore, the specified registers become **PERMANENTLY** protected against data changes. As in the PRWRITE instruction the PRE and PE pins **must** be held high while loading the instruction, and after loading the PRDS instruction the PRE and PE pins become "don't care".

Note that a PREN instruction must **immediately** precede a PRDS instruction.

### Instruction Set for the NM93CS06L and NM93CS46L

Instruction	SB	Op Code	Address	Data	PRE	PE	Comments
READ	1	10	A5-A0		0	Х	Reads data stored in memory, starting at specified address.
WEN	1	00	11XXXX		0	1	Enable all programming modes.
WRITE	1	01	A5-A0	D15-D0	0	1	Writes address if unprotected.
WRALL	1	00	01XXXX	D15-D0	0	1	Writes all registers. Valid only when Protect Register is cleared.
WDS	1	00	00XXXX		0	Х	Disables all programming modes.
PRREAD	1	10	XXXXXX		1	Х	Reads address stored in Protect Register.
PREN	1	00	11XXXX		1	1	Must immediately precede PRCLEAR, PRWRITE, and PRDS instructions.
PRCLEAR	1	11	111111		1	1	Clears the Protect Register so that no registers are protected from WRITE.
PRWRITE	1	01	A5-A0		1	1	Programs address into Protect Register. Thereafter, memory addresses ≥ the address in Protect Register are protected from WRITE.
PRDS	1	00	000000		1	1	ONE TIME ONLY instruction after which the address in the Protect Register cannot be altered.

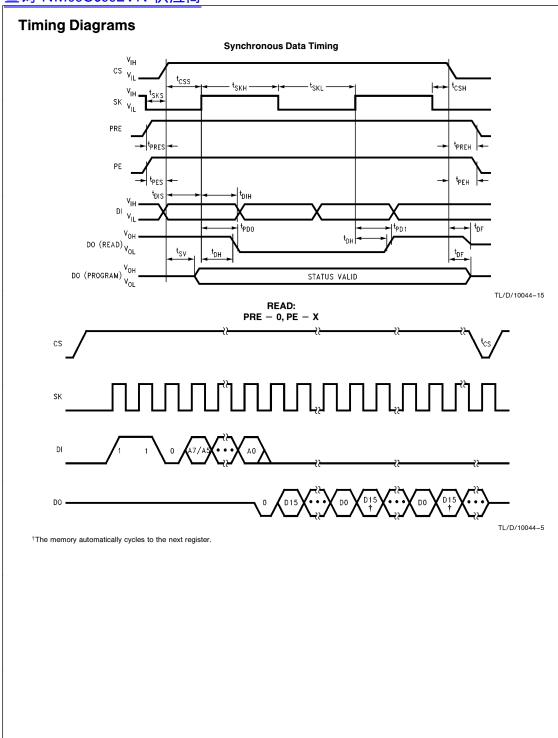
Note: Address bits A5 and A4 become "Don't Care" for the NM93CS06L.

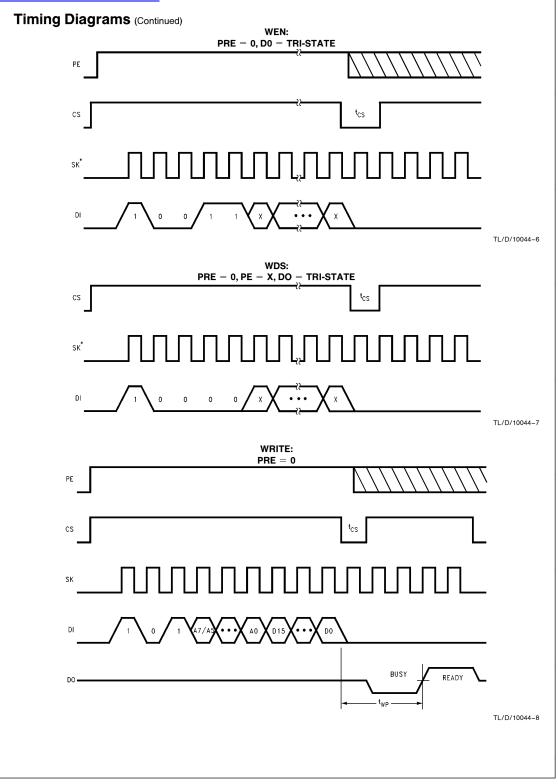
### Instruction Set for the NM93CS56L and NM93CS66L

Instruction	SB	Op Code	Address	Data	PRE	PE	Comments
READ	1	10	A7-A0		0	Х	Reads data stored in memory, starting at specified address.
WEN	1	00	11XXXXXX		0	1	Enable all programming modes.
WRITE	1	01	A7-A0	D15-D0	0	1	Writes address if unprotected.
WRALL	1	00	01XXXXXX	D15-D0	0	1	Writes all registers. Valid only when Protect Register is cleared.
WDS	1	00	00XXXXXX		0	Х	Disables all programming modes.
PRREAD	1	10	XXXXXXX		1	Х	Reads address stored in Protect Register.
PREN	1	00	11XXXXXX		1	1	Must immediately precede PRCLEAR, PRWRITE, and PRDS instructions.
PRCLEAR	1	11	11111111		1	1	Clears the "protect register" so that no registers are protected from WRITE.
PRWRITE	1	01	A7-A0		1	1	Programs address into Protect Register. Thereafter, memory addresses ≥ the address in Protect Register are protected from WRITE.
PRDS	1	00	00000000		1	1	<b>ONE TIME ONLY</b> instruction after which the address in the Protect Register cannot be altered.

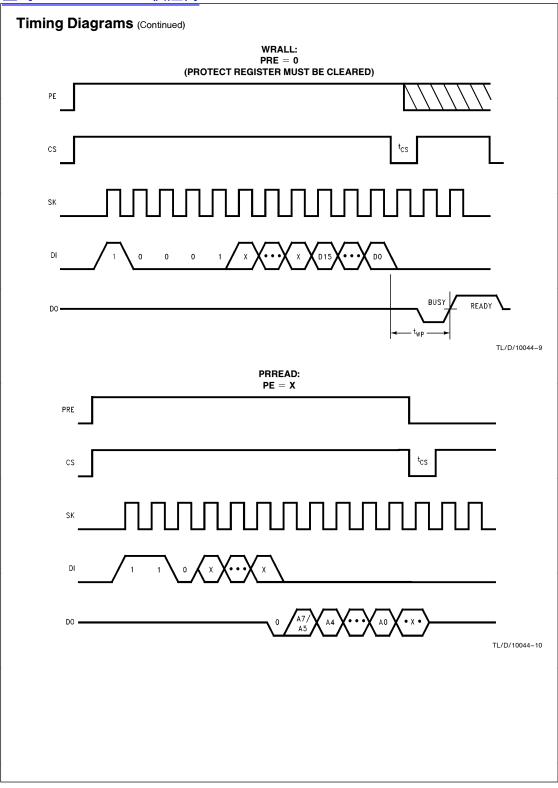
Note: Address bit A7 becomes "Don't Care" for the NM93CS56L.

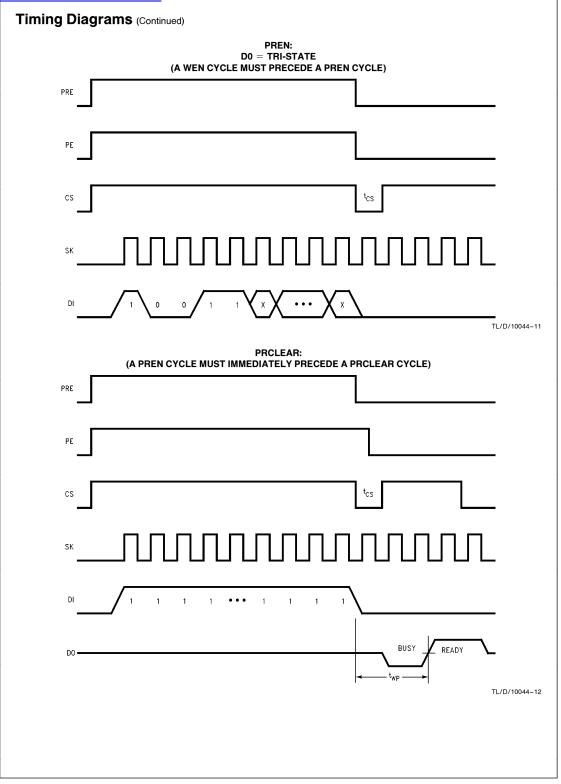
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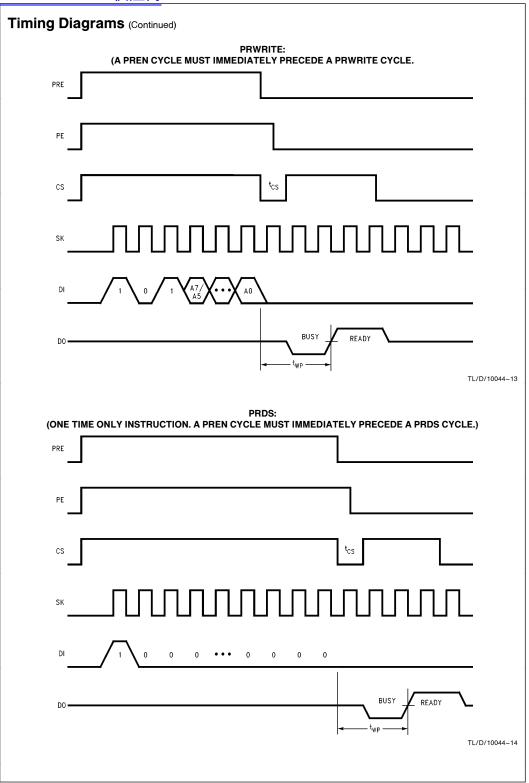


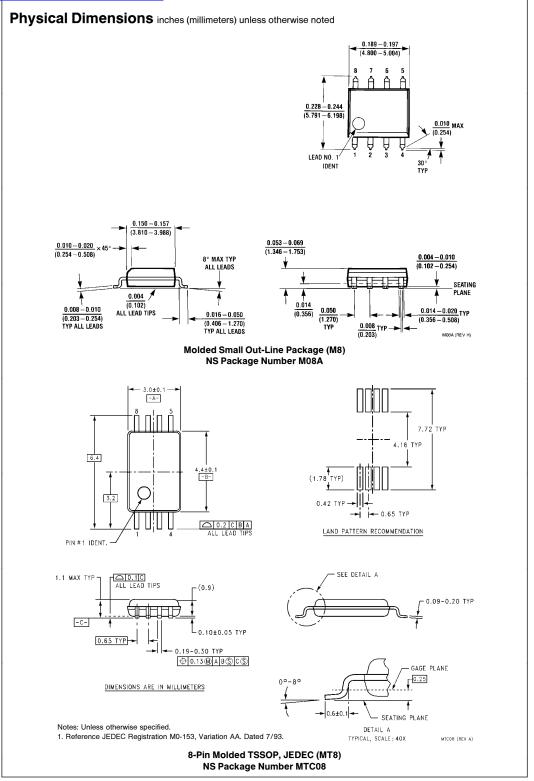


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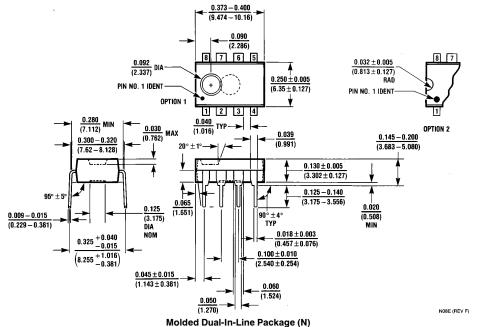








### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NS Package Number N08E

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